Advanced Power MOSFET

FEATURES

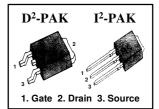
- Avalanche Rugged Technology
- Rugged Gate Oxide Technology
- Lower Input Capacitance
- Improved Gate Charge
- Extended Safe Operating Area
- 175°C Operating Temperature
- Lower Leakage Current : 10 µA (Max.) @ V_{DS} = -60V
- Low $R_{DS(ON)}$: 0.22 Ω (Typ.)

SFW/I2955

 BV_{DSS} = -60 V

 $R_{DS(on)} = 0.3\Omega$

 $I_{\rm D} = -9.4 \, {\rm A}$



Absolute Maximum Ratings

Symbol	Characteristic	Value	Units
V _{DSS}	Drain-to-Source Voltage	-60	V
1	Continuous Drain Current (T _C =25°C)	-9.4	A
۱ _D	Continuous Drain Current (T _c =100°C)	-6.6	
I _{DM}	Drain Current-Pulsed	-38	Α
V _{GS}	Gate-to-Source Voltage	<u>+</u> 20	V
E _{AS}	Single Pulsed Avalanche Energy (2)	151	mJ
I _{AR}	Avalanche Current ①	-9.4	Α
E _{AR}	Repetitive Avalanche Energy	4.9	mJ
dv/dt	Peak Diode Recovery dv/dt 3	-5.5	V/ns
	Total Power Dissipation (T _A =25°C) *	3.8	W
P _D	Total Power Dissipation (T _C =25°C)	49	W
	Linear Derating Factor	0.33	W/ºC
тт	Operating Junction and	EE to 17E	
T_J , T_STG	Storage Temperature Range	- 55 to +175	0.5
TL	Maximum Lead Temp. for Soldering	200	°C
	Purposes, 1/8" from case for 5-seconds	300	

Thermal Resistance

Symbol	Characteristic	Тур.	Max.	Units
R _{θJC}	Junction-to-Case		3.06	
R _{θJA}	Junction-to-Ambient *		40	°C/W
R _{θJA}	Junction-to-Ambient		62.5	

* When mounted on the minimum pad size recommended (PCB Mount).



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Rev. B

P-CHANNEL POWERMOSFET

Symbol	Characteristic	Min.	Тур.	Max.	Units	Test Condition
BV _{DSS}	Drain-Source Breakdown Voltage	-60			V	$V_{GS}=0V,I_{D}=-250\mu A$
$\Delta BV/\Delta T_J$	Breakdown Voltage Temp. Coeff.		-0.04	-	V/°C	I _D =-250μA See Fig 7
V _{GS(th)}	Gate Threshold Voltage	-2.0		-4.0	V	V_{DS} =-5V,I _D =-250 μ A
	Gate-Source Leakage, Forward			-100	nA	V _{GS} =-20V
GSS	Gate-Source Leakage, Reverse			100		V _{GS} =20V
				-10	•	V _{DS} =-60V
I _{DSS}	Drain-to-Source Leakage Current			-100	μA	V_{DS} =-48V, T_{C} =150°C
	Static Drain-Source				0	
R _{DS(on)}	On-State Resistance			0.3	Ω	V_{GS} =-10V,I _D =-4.7A ④
9 _{fs}	Forward Transconductance		4.0		Ω	V _{DS} =-30V,I _D =-4.7A ④
C _{iss}	Input Capacitance		465	600		V _{GS} =0V,V _{DS} =-25V,f =1MHz
C _{oss}	Output Capacitance		140	215	pF	See Fig 5
C _{rss}	Reverse Transfer Capacitance		40	60		See Fig 5
t _{d(on)}	Turn-On Delay Time		11	30		V _{DD} =-30V,I _D =-9.4A,
t _r	Rise Time		21	50	ns	$R_{G}=18\Omega$
t _{d(off)}	Turn-Off Delay Time		29	65	115	
t _f	Fall Time		20	50		See Fig 13 ④⑤
Qg	Total Gate Charge		15	19		V_{DS} =-48V, V_{GS} =-10V,
Q _{gs}	Gate-Source Charge		2.9		nC	I _D =-9.4A
Q _{gd}	Gate-Drain("Miller") Charge		6.0			See Fig 6 & Fig 12 ④⑤

Electrical Characteristics ($T_C=25^{\circ}C$ unless otherwise specified)

Source-Drain Diode Ratings and Characteristics

Symbol	Characteristic		Min.	Тур.	Max.	Units	Test Condition	
ا _s	Continuous Source Current				-9.4	А	Integral reverse pn-diode	
I _{SM}	Pulsed-Source Current	0			-38	A	in the MOSFET	
V _{SD}	Diode Forward Voltage	4			-3.8	V	$T_J=25^{\circ}C,I_S=-9.4A,V_{GS}=0V$	
t _{rr}	Reverse Recovery Time			80		ns	T _J =25°C,I _F =-9.4A	
Q _{rr}	Reverse Recovery Charge			0.22		μC	$di_F/dt=100A/\mu s$	

Notes :

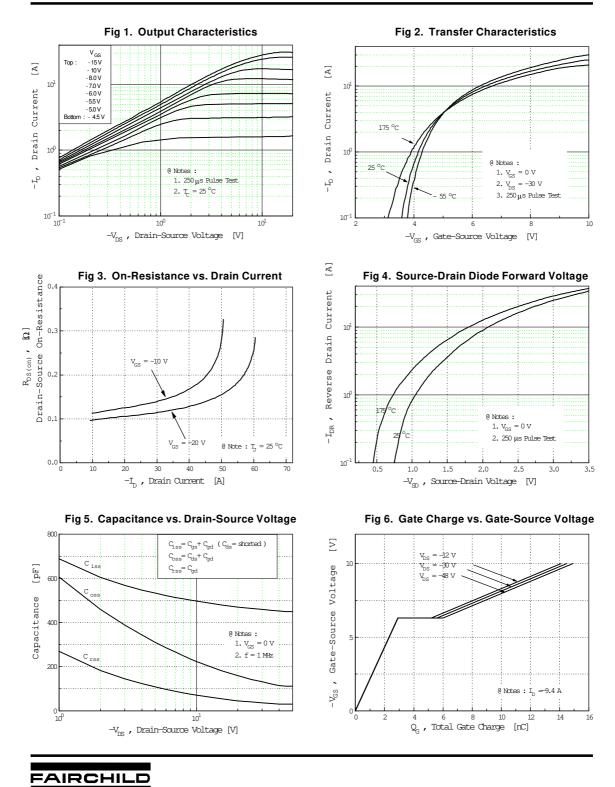
- () Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature
- (2) L=2.0mH, I_{AS} =-9.4A, V_{DD} =-25V, R_{G} =27 Ω^{*} , Starting T_{J} =25°C (3) $I_{SD} \leq$ -9.4A, di/dt \leq 250A/ μ s, $V_{DD} \leq$ BV_{DSS}, Starting T_{J} =25°C (4) Pulse Test : Pulse Width = 250 μ s, Duty Cycle \leq 2%
- 5 Essentially Independent of Operating Temperature



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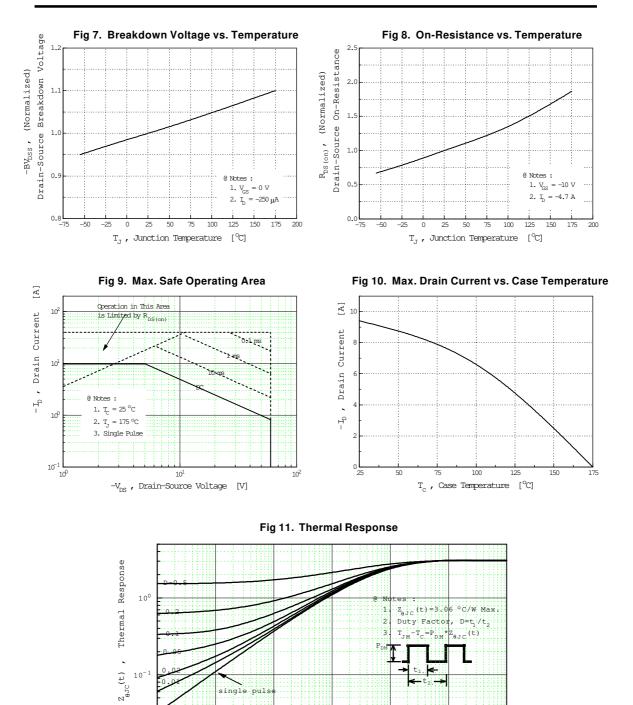
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10

10

10

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 ${\bf t}_1$, Square Wave Pulse Duration

10

10

[sec]

10

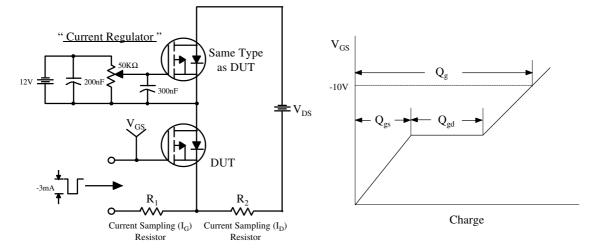
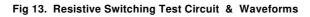


Fig 12. Gate Charge Test Circuit & Waveform

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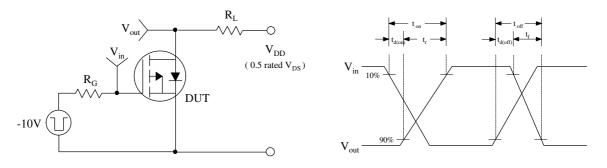
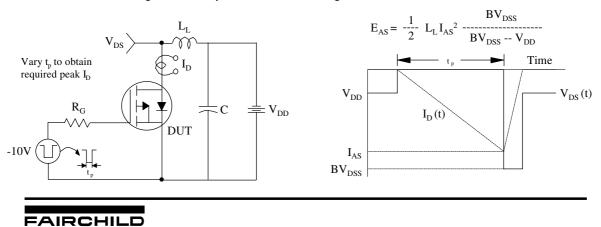
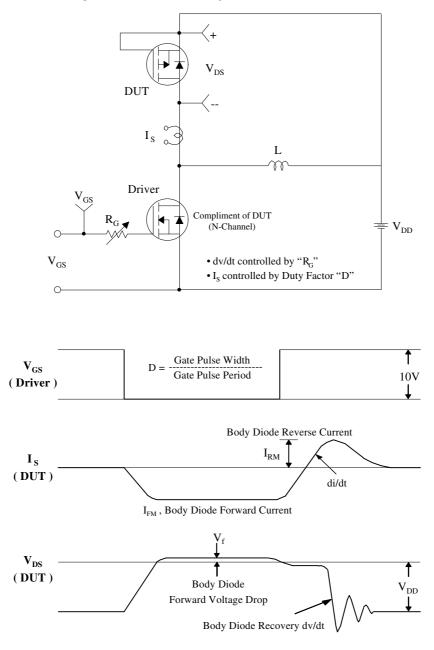
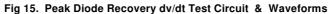


Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms









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